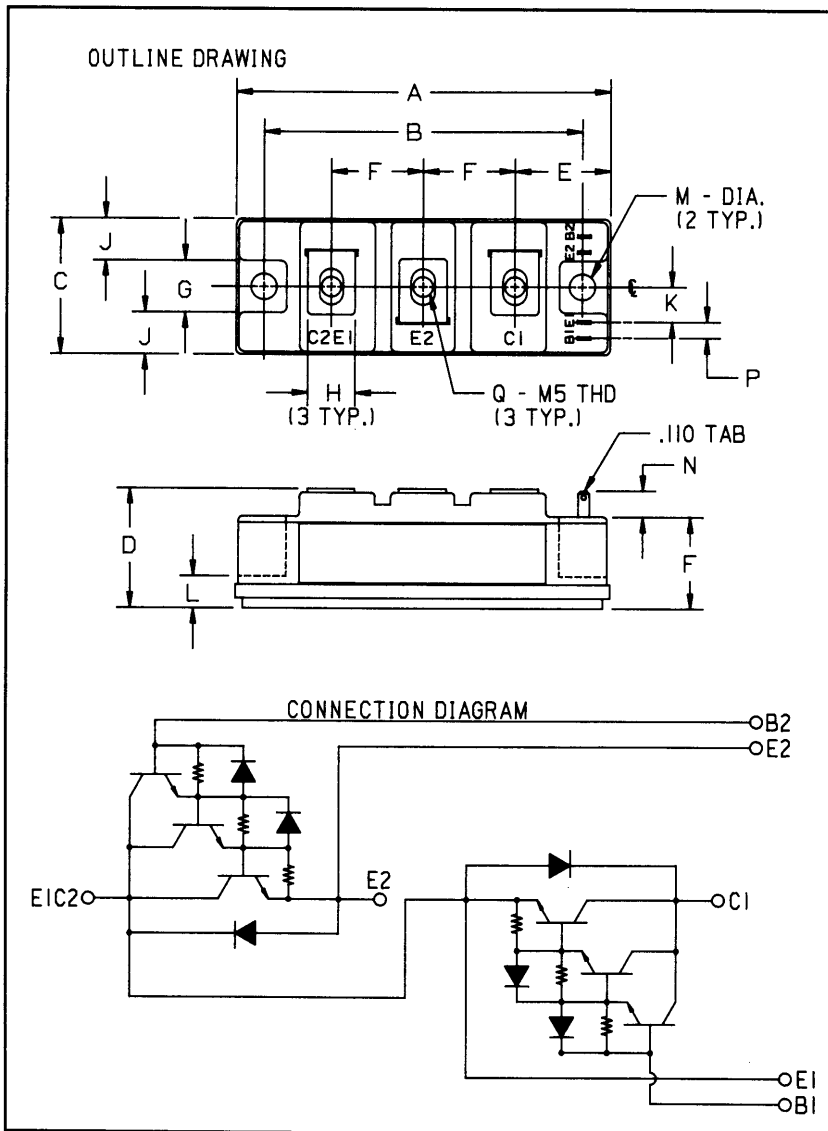


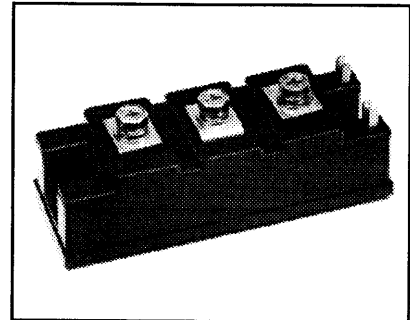
Dual Darlington Transistor Module 50 Amperes/1200 Volts



Outline Drawing

Dimensions	Inches	Millimeters
A	3.701 Max.	94 Max.
B	3.150 ± 0.010	80 ± 0.25
C	1.339 Max.	34 Max.
D	1.181 Max.	30 Max.
E	0.945	24
F	0.906	23
G	0.512	13
H	0.472	12

Dimensions	Inches	Millimeters
J	0.413	10.5
K	0.344	8.75
L	0.315	8
M	0.256 Dia.	6.5 Dia.
N	0.256 Min.	6.5 Min.
P	0.157	4
Q	M5 Metric	M5



Description:

The Powerex Dual Darlington Transistor Modules are high power devices designed for use in switching applications. The modules are isolated, consisting of two Darlington Transistors with each transistor having a reverse parallel connected high-speed diode.

Features:

- ☐ Isolated Mounting
- ☐ Planar Chips
- ☐ Discrete Fast Recovery Feedback Diode
- ☐ High Gain (h_{FE})
- ☐ Quick Connect Base-Emitter Signal Terminals
- ☐ Base-Emitter Speed-up Diodes

Applications:

- ☐ AC Motor Control
- ☐ DC Motor Control
- ☐ Switching Power Supplies
- ☐ Inverters

Ordering Information:

Example: Select the complete ten digit module part number you desire from the table - i.e. KD221205A7 is a 1200 Volt, 50 Ampere Dual Darlington Module with a gain of 75 at rated current (50 Amperes).

Type	$V_{CE(sus)}$ Volts (X 100)	Current Rating Amperes (X 10)
KD22	12	05



Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (412) 925-7272

KD221205A7
Dual Darlington Transistor Module
 50 Amperes/1200 Volts

Absolute Maximum Ratings, $T_j = 25^\circ\text{C}$ unless otherwise specified

Ratings	Symbol	KD221205A7	Units
Junction Temperature	T_j	-40 to 150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-40 to 125	$^\circ\text{C}$
Collector-Emitter Sustaining Voltage, $V_{BE} = -2\text{V}$	$V_{CEV(sus)}$	1200	Volts
Collector-Base Voltage	V_{CBO}	1200	Volts
Emitter-Base Voltage	V_{EBO}	7	Volts
Collector-Emitter Voltage, $V_{BE} = -2\text{V}$	V_{CEV}	1200	Volts
Continuous Collector Current	I_C	50	Amperes
Diode Forward Current	I_{FM}	530	Amperes
Continuous Base Current	I_B	3	Amperes
Diode Surge Current	I_{FSM}	500	Amperes
Power Dissipation (Each Transistor)	P_t	400	Watts
Max. Mounting Torque M5 Terminal Screws	—	17	in.-lb.
Max. Mounting Torque M6 Mounting Screws	—	26	in.-lb.
Module Weight (Typical)	—	210	Grams
V Isolation	V_{RMS}	2500	Volts

Electrical Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

Characteristics		Symbol	Test Conditions	Min.	Typ.	Max.	Units
Collector Cutoff Current		I_{CEV}	$V_{CE} = 1200V, V_{BE} = -2V$	—	—	1	mA
			$V_{CE} = 1200V, V_{BE} = -2V, T_C = 125^{\circ}C$	—	—	10	mA
Emitter Cutoff Current		I_{EBO}	$V_{EB} = 7V$	—	—	200	mA
DC Current Gain		h_{FE}	$I_C = 50A, V_{CE} = 5V$	75	—	—	—
Diode Forward Voltage		V_{FM}	$I_{FM} = 50A$	—	—	1.8	Volts
Collector-Emitter Saturation Voltage		$V_{CE(sat)}$	$I_C = 50A, I_B = 1A$	—	—	3.0	Volts
Base-Emitter Saturation Voltage		$V_{BE(sat)}$	$I_C = 50A, I_B = 1A$	—	—	3.5	Volts
Resistive Load	Turn-on	t_{on}	$V_{CC} = 600V$	—	—	2.5	μs
	Storage Time	t_s	$I_C = 50A$	—	—	15	μs
Switch Times		Fall Time	$I_{B1} = 1A, I_{B2} = -1A$	—	—	3.0	μs

Thermal and Mechanical Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance, Case-to-Sink	$R_{\theta(c-s)}$	Per 1/2 Module	—	—	0.15	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Case	$R_{\theta(j-c)}$	Transistor Part	—	—	0.31	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Case	$R_{\theta(j-c)}$	Diode Part	—	—	1.2	$^\circ\text{C/W}$

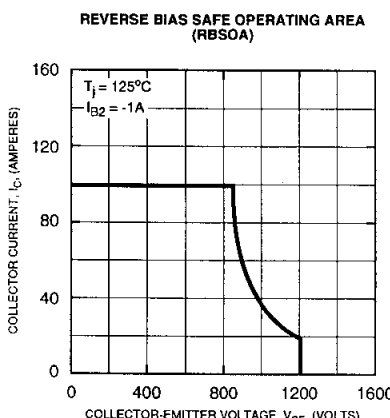
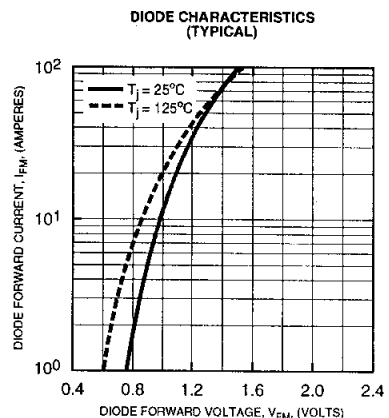
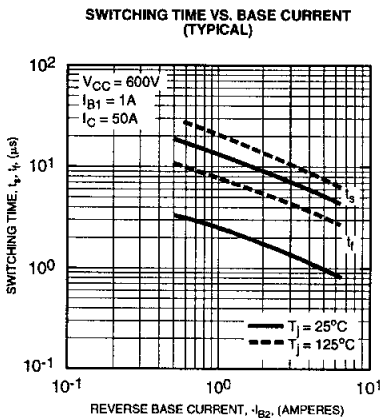
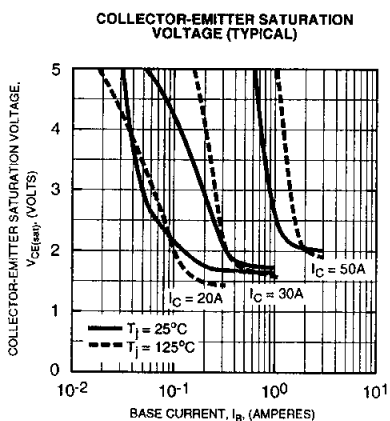
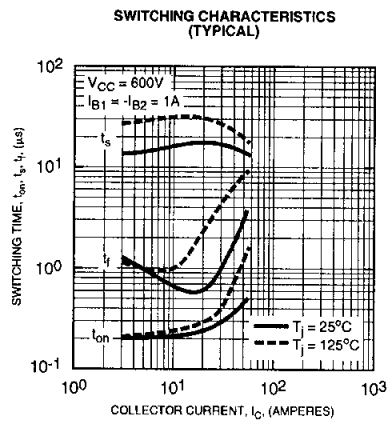
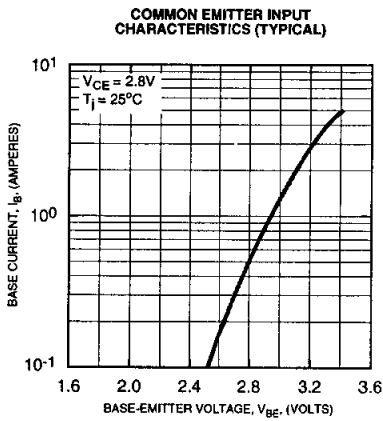
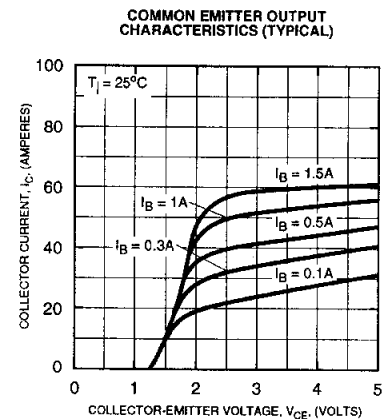
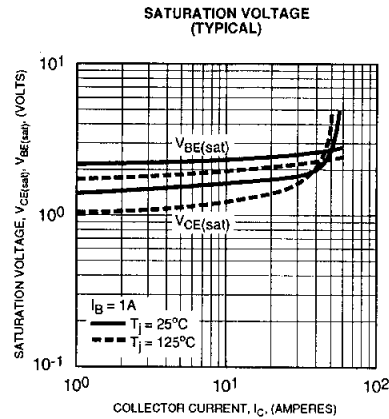
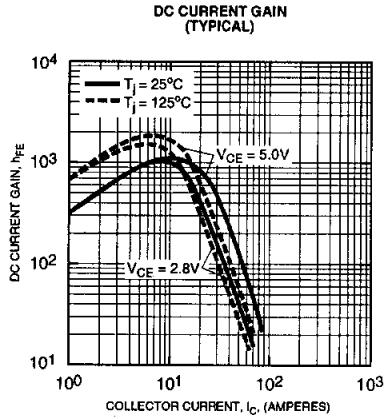


Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (412) 925-7272

KD221205A7

Dual Darlington Transistor Module

50 Amperes/1200 Volts



KD221205A7
Dual Darlington Transistor Module
 50 Amperes/1200 Volts

